

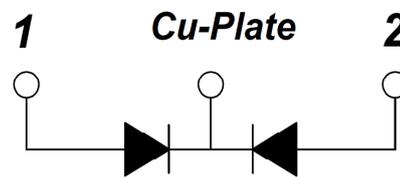
PRODUCT FEATURES

- Ultrafast Recovery Time
- Low Recovery Loss
- Low Forward Voltage
- Low Leakage Current
- Low Inductance Package



APPLICATIONS

- Inversion Welder
- Uninterruptible Power Supply
- Plating Power Supply
- Ultrasonic Cleaner and Welder
- Converter & Chopper
- PFC



ABSOLUTE MAXIMUM RATINGS

$T_C = 25^\circ\text{C}$ unless otherwise specified

| Symbol | Parameter/Test Conditions | | Values | Unit |
|--------------|--|--|-------------|---------------------------|
| V_R | Maximum D.C. Reverse Voltage | | 400 | V |
| V_{RRM} | Maximum Repetitive Reverse Voltage | | | |
| $I_{F(AV)}$ | Average Forward Current | $T_C = 110^\circ\text{C}$, Per Diode | 100 | A |
| | | $T_C = 110^\circ\text{C}$, Per Module | 200 | |
| $I_{F(RMS)}$ | RMS Forward Current | $T_C = 110^\circ\text{C}$, Per Diode | 150 | |
| I_{FSM} | Non Repetitive Surge Forward Current | $T_J = 45^\circ\text{C}$, $t = 10\text{ms}$, Sine, peak value | 1200 | |
| | | $T_J = 45^\circ\text{C}$, $t = 8.3\text{ms}$, Sine, peak value | 1310 | |
| I^2t | For Fusing | $T_J = 45^\circ\text{C}$, $t = 10\text{ms}$, Sine, peak value | 7200 | A ² S |
| | | $T_J = 45^\circ\text{C}$, $t = 8.3\text{ms}$, Sine, peak value | 7122 | |
| P_D | Power Dissipation | | 625 | W |
| T_J | Junction Temperature | | -40 to +150 | $^\circ\text{C}$ |
| T_{STG} | Storage Temperature Range | | -40 to +125 | $^\circ\text{C}$ |
| Torque | Module to Sink | Recommended (M6) | 3~4.7 | Nm |
| | Module Electrodes | Recommended (M6) | 3~4.7 | Nm |
| R_{thJC} | Junction to Case Thermal Resistance(Per Diode) | | 0.2 | $^\circ\text{C}/\text{W}$ |
| Weight | | | 92 | g |

ELECTRICAL CHARACTERISTICS

$T_C=25^{\circ}\text{C}$ unless otherwise specified

| Symbol | Parameter/Test Conditions | | Min. | Typ. | Max. | Unit |
|-----------|---|---|------|------|------|------|
| I_{RM} | Maximum Reverse Leakage Current | $V_R = 400\text{V}$ | | | 0.5 | mA |
| | | $V_R = 400\text{V}, T_J = 125^{\circ}\text{C}$ | | | 10 | |
| V_F | Forward Voltage | $I_F=100\text{A}$ | | 1.5 | 2.0 | V |
| | | $I_F=100\text{A}, T_J=125^{\circ}\text{C}$ | | 1.2 | | |
| t_{rr} | Reverse Recovery Time ($I_F = 1\text{A}, dI_F/dt = -200\text{A}/\mu\text{s}, V_R = 30\text{V}$) | | | 35 | | ns |
| t_{rr} | Reverse Recovery Time | $I_F=100\text{A}, V_R=200\text{V},$ | | 60 | | ns |
| I_{RRM} | Maximum Reverse Recovery Current | $dI_F/dt = -200\text{A}/\mu\text{s}$ | | 9 | | A |
| t_{rr} | Reverse Recovery Time | $I_F= 100\text{A}, V_R = 200\text{V},$ | | 85 | | ns |
| I_{RRM} | Maximum Reverse Recovery Current | $dI_F/dt = -200\text{A}/\mu\text{s}, T_J=125^{\circ}\text{C}$ | | 15 | | A |

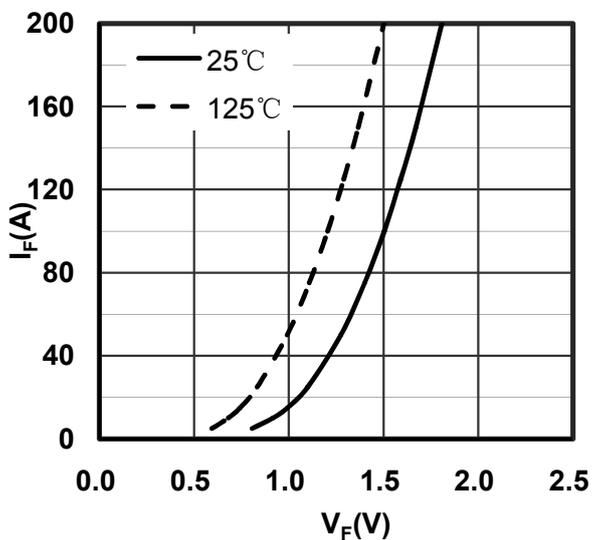


Figure 1. Forward Voltage Drop vs Forward Current

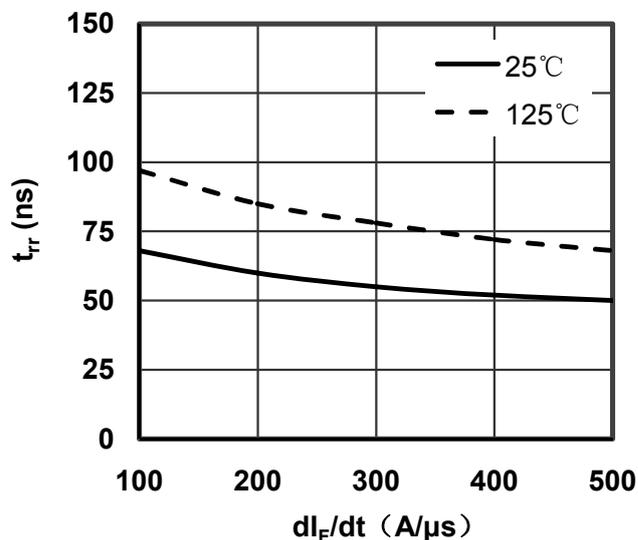


Figure 2. Reverse Recovery Time vs dI_F/dt

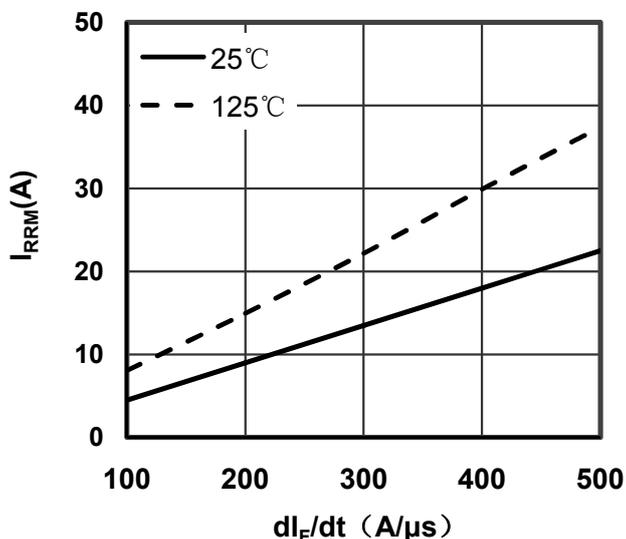


Figure 3. Reverse Recovery Current vs dI_F/dt

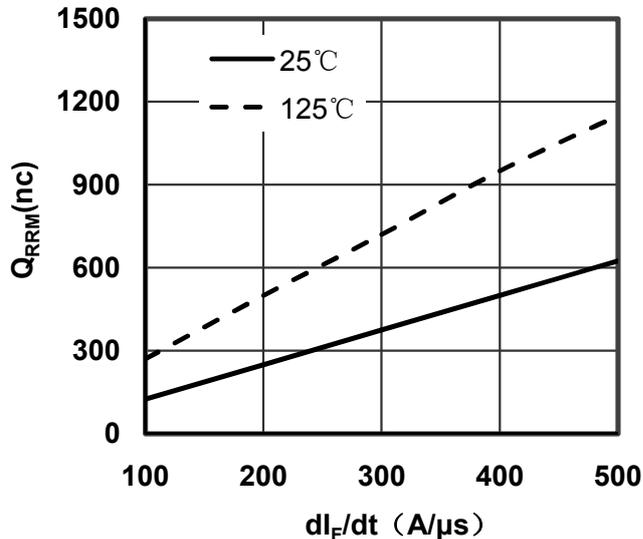


Figure 4. Reverse Recovery Charge vs dI_F/dt

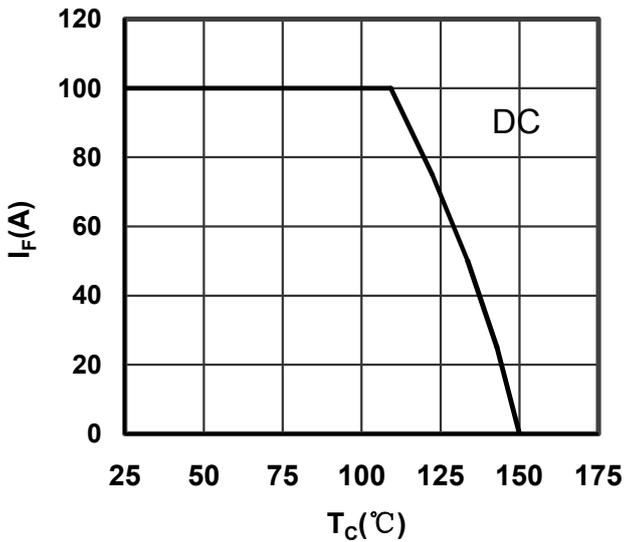


Figure 5. Forward current vs Case temperature

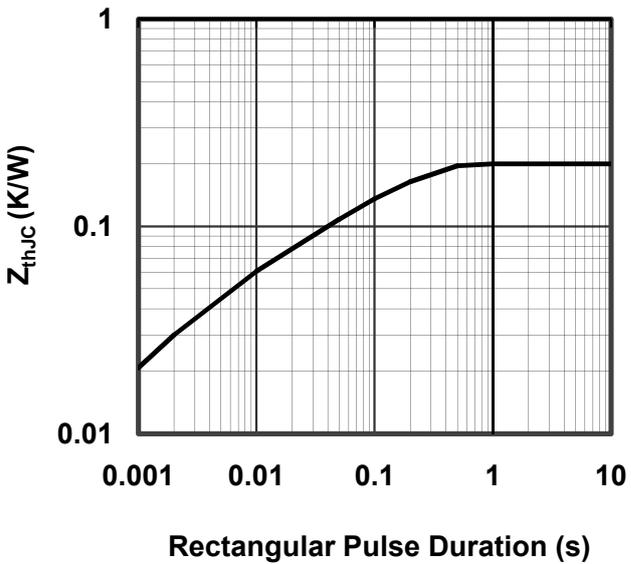
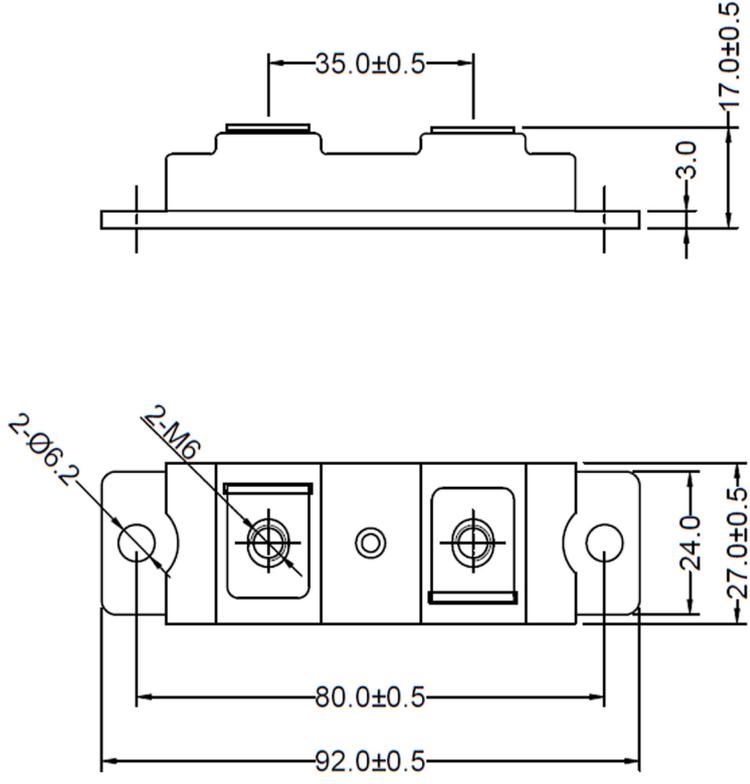


Figure 6. Transient Thermal Impedance



Dimensions in (mm)
Figure 7. Package Outline